SKT 491

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	SEMIKRON SKT 491/1

Capsule Thyristor	I _{TAV}	sin. 180; T _c = 100 (85) °C	321 (452)	A
	I _D	2 x P8/180; T _a = 45 °C; B2 / B6	320 / 450	А
		2 x P8/180F; T _a = 35 °C; B2 / B6	760 /1000	А
Line Thyristor	I _{RMS}	2 x P8/180; T _a = 45 °C; W1C	350	А
	I _{TSM}	T _{vi} = 25 °C; 10 ms	8000	А
		T _{vi} = 125 °C; 10 ms	7000	А
SKT 491	i²t	T _{vj} = 25 °C; 8,3 10 ms	320000	A²s
••••		T _{vj} = 125 °C; 8,3 10 ms	245000	A²s
	V _T	T _{vi} = 25 °C; I _T = 1500 A	max. 2,1	V
	V _{T(TO)}	T _{vi} = 125 °C	1,1	V
	r _T	T _{vi} = 125 °C	0,7	mΩ
	I _{DD} ; I _{RD}	$T_{vj} = 125 \text{ °C}; V_{RD} = V_{RRM}; V_{DD} = V_{DRM}$	max. 50	mA
	t _{gd}	T _{vi} = 25 °C; I _G = 1 A; di _G /dt = 1 A/μs	1	μs
Features	t _{gr}	$V_{\rm D} = 0.67 * V_{\rm DRM}$	1	μs
Hermetic metal case with ceramic	(di/dt) _{cr}	T _{vi} = 125 °C	max. 125	A/µs
insulator	(dv/dt) _{cr}	$T_{vi} = 125 \text{ °C}$	max. 1000	V/µs
Capsule package for double	t _q	$T_{vi}^{vj} = 125 \text{ °C}$	50 150	μs
sided cooling	I _H	T _{vi} = 25 °C; typ. / max.	150 / 500	mA
Shallow design with single sided	IL	$T_{vi} = 25 \text{ °C } R_{G} = 33 \Omega; \text{ typ. / max.}$	0,5 / 2	mA
cooling	V _{GT}	T _{vi} = 25 °C; d.c.	min. 3	V
 International standard case 	I _{GT}	$T_{vi}^{vj} = 25 ^{\circ}C; d.c.$	min. 250	mA
Off-state and reverse voltages up	V _{GD}	T _{vi} = 125 °C; d.c.	max. 0,25	V
to 1800 V	I _{GD}	T _{vi} = 125 °C; d.c.	max. 10	mA
Amplifying gate	R _{th(j-c)}	cont.; DSC	0,045	K/W
	R _{th(j-c)}	sin. 180; DSC / SSC	0,047 / 0,1	K/W
Typical Applications	R _{th(j-c)}	rec. 120; DSC / SSC	0,054 / 0,113	K/W
DC motor control	R _{th(c-s)}	DSC / SSC	0,012 / 0,024	K/W
(e.g. for machine tools)	T _{vj}		- 40 + 125	°C
Controlled rectifiers	T _{stg}		- 40 + 130	°C
(e. g. for battery charging)	V _{isol}		-	V~
AC controllers	F	mounting force	5,2 8	kN
(e. g. for temperature control)	a		0,2 0	m/s ²
 Recommended snubber network 	m	approx.	105	g
				э
e. g. for $V_{VRMS} \le 400 V$:	Case		B 11	
R = 33 Ω/32 W, C = 0,47 μF				

 V_{RSM}

V

500

900

1300

1500

1700

1900

Symbol Conditions

 $\rm V_{RRM}, \, V_{DRM}$

V

400

800

1200

1400

1600

1800

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SKT 491/14E

SKT 491/16E

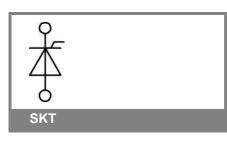
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I_{TRMS} = 1000 A (maximum value for continuous operation)

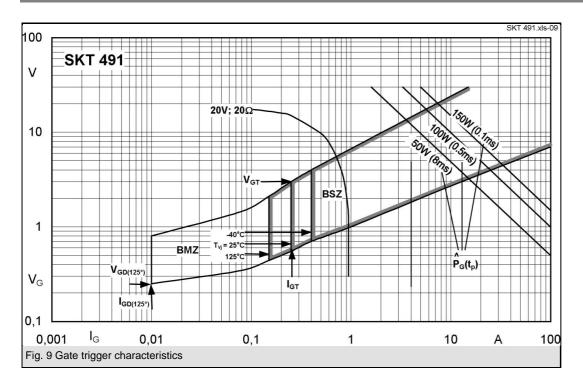
 I_{TAV} = 490 A (sin. 180; DSC; T_c = 80 °C)

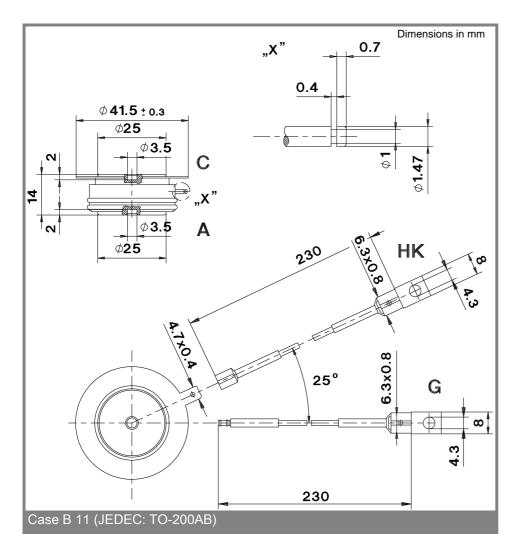
Values

Units



SKT 491





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